



IMPORTANT NOTICE

10 December 2015

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors



1. Product profile

1.1 General description

Ultrafast, dual common cathode, epitaxial rectifier diodes in a SOT78 (TO-220AB) and a SOT428 (DPAK) plastic package.

1.2 Features

- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- Low thermal resistance
- Low forward voltage drop
- High thermal cycling performance

1.3 Applications

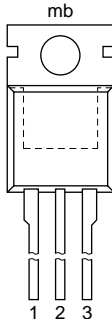
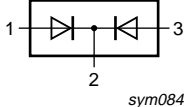
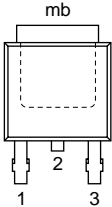
- Output rectifiers in high-frequency switched-mode power supplies

1.4 Quick reference data

- $V_{RRM} \leq 200 \text{ V}$
- $V_F \leq 0.895 \text{ V}$
- $I_{O(AV)} \leq 10 \text{ A}$
- $t_{rr} = 10 \text{ ns (typ)}$

2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Symbol
1	anode 1	 <p style="text-align: center;">SOT78 (3-lead TO-220AB)</p>	 <p style="text-align: right;"><i>sym084</i></p>
2	cathode [1]		
3	anode 2		
mb	mounting base; cathode	 <p style="text-align: center;">SOT428 (DPAK)</p>	

[1] It is not possible to connect to pin 2 of the SOT428 package.

3. Ordering information

Table 2. Ordering information

Type number	Package		Version
	Name	Description	
BYQ28E-200	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78
BYQ28ED-200	DPAK	plastic single-ended surface-mounted package (DPAK); 3-leads (one lead cropped)	SOT428

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	200	V
V_{RWM}	crest working reverse voltage		-	200	V
V_R	reverse voltage	square waveform; $\delta = 1.0$	-	200	V
$I_{O(AV)}$	average output current	square waveform; $\delta = 0.5$; $T_{mb} \leq 119\text{ °C}$; both diodes conducting	-	10	A
I_{FRM}	repetitive peak forward current	$t_p = 25\ \mu\text{s}$; square waveform; $\delta = 0.5$; $T_{mb} \leq 119\text{ °C}$; per diode	-	10	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$; sinusoidal waveform; per diode	-	50	A
		$t = 8.3\text{ ms}$; sinusoidal waveform; per diode	-	55	A
I_{RM}	peak reverse recovery current	$t_p = 2\ \mu\text{s}$; $\delta = 0.001$	-	0.2	A
I_{RSM}	non-repetitive peak reverse current	$t_p = 100\ \mu\text{s}$	-	0.2	A
T_{stg}	storage temperature		-40	+150	°C
T_j	junction temperature		-	150	°C
Electrostatic discharge					
V_{ESD}	electrostatic discharge voltage	all pins; human body model; $C = 250\text{ pF}$; $R = 1.5\text{ k}\Omega$	-	8	kV

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; per diode; see Figure 1	-	-	4.5	K/W
		with heatsink compound; both diodes conducting	-	-	3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; SOT78	-	60	-	K/W
		SOT428	[1]	50	-	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

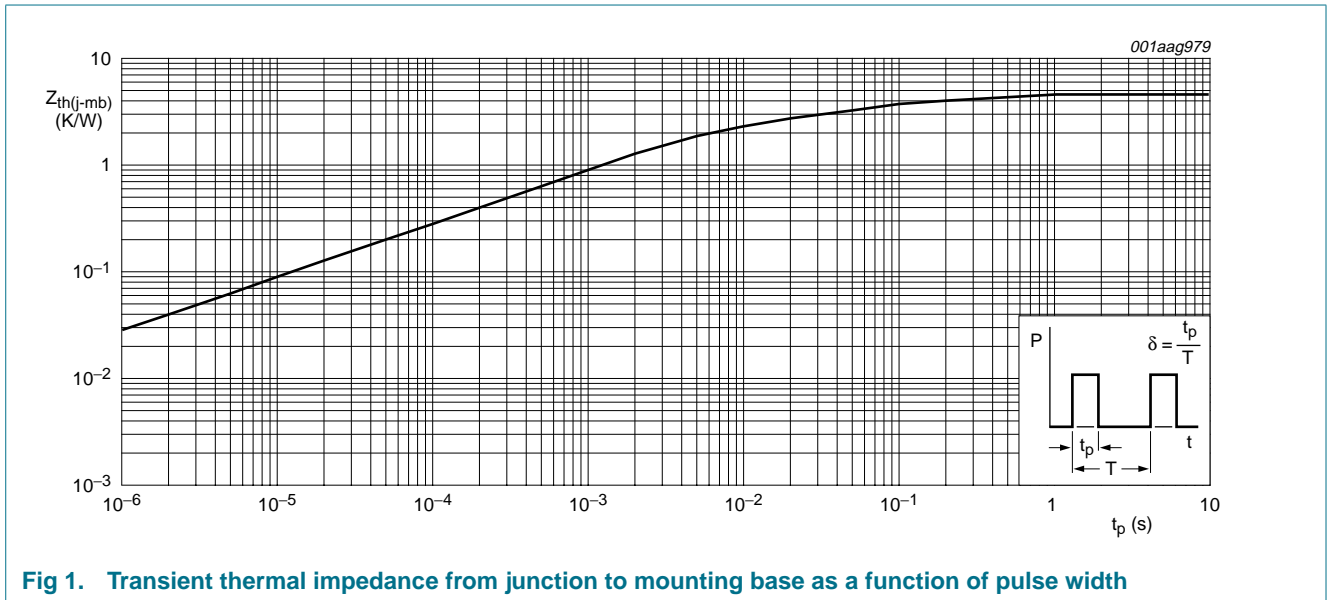


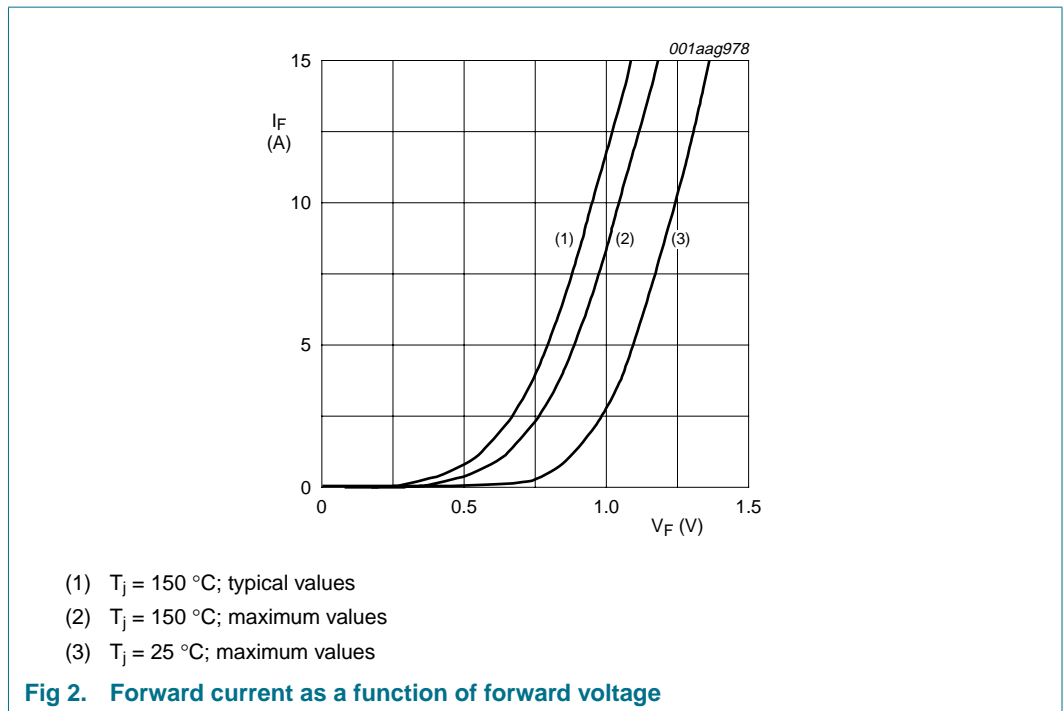
Fig 1. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 5. Characteristics

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 5\text{ A}$; $T_j = 150\text{ }^\circ\text{C}$; see Figure 2	-	0.8	0.895	V
		$I_F = 5\text{ A}$; see Figure 2	-	0.95	1.1	V
		$I_F = 10\text{ A}$; see Figure 2	-	1.1	1.25	V
I_R	reverse current	$V_R = 200\text{ V}$	-	2	10	μA
		$V_R = 200\text{ V}$; $T_j = 100\text{ }^\circ\text{C}$	-	0.1	0.2	mA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 2\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 20\text{ A}/\mu\text{s}$; see Figure 3	-	4	9	nC
t_{rr}	reverse recovery time	ramp recovery; $I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 100\text{ A}/\mu\text{s}$; see Figure 3	-	15	25	ns
		step recovery; when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$	-	10	20	ns
I_{RM}	peak reverse recovery current	$I_F = 5\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 50\text{ A}/\mu\text{s}$; see Figure 3	-	0.5	0.7	A
V_{FR}	forward recovery voltage	$I_F = 1\text{ A}$; $di_F/dt = 10\text{ A}/\mu\text{s}$; see Figure 4	-	1	-	V



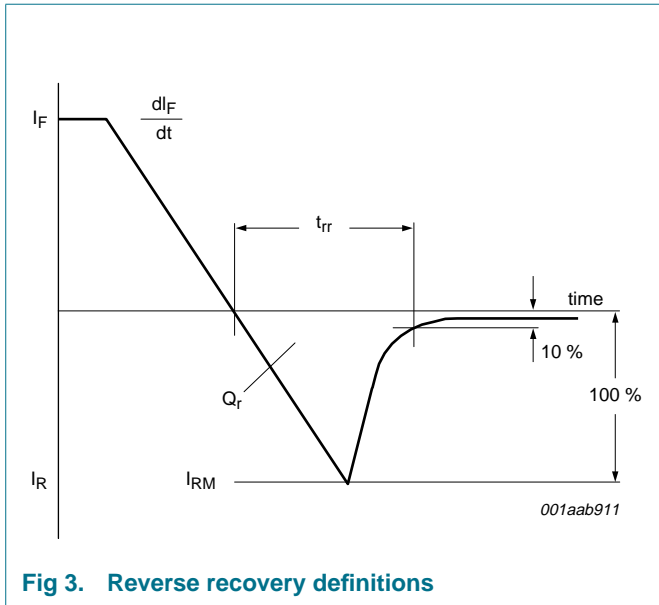


Fig 3. Reverse recovery definitions

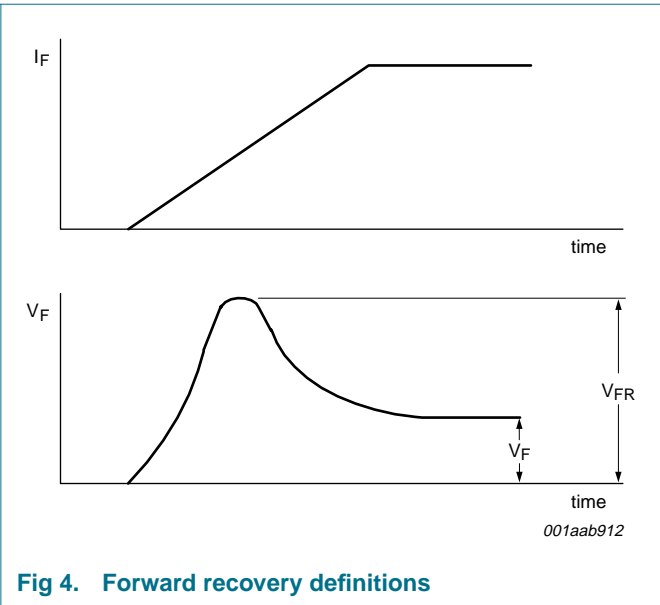


Fig 4. Forward recovery definitions

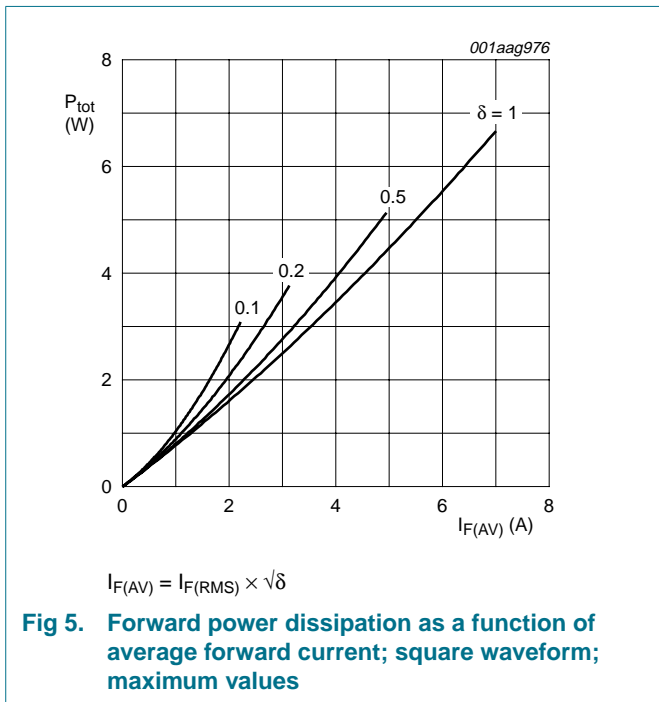


Fig 5. Forward power dissipation as a function of average forward current; square waveform; maximum values

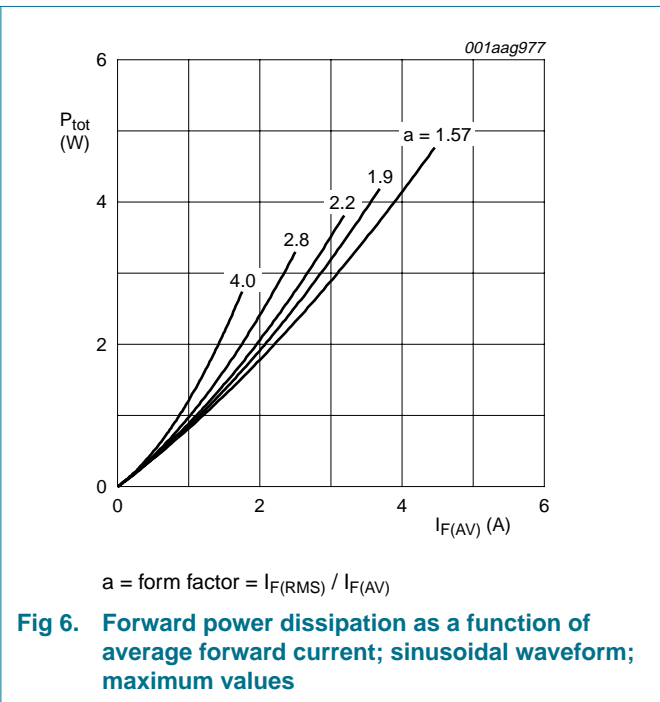
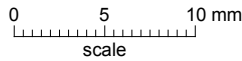
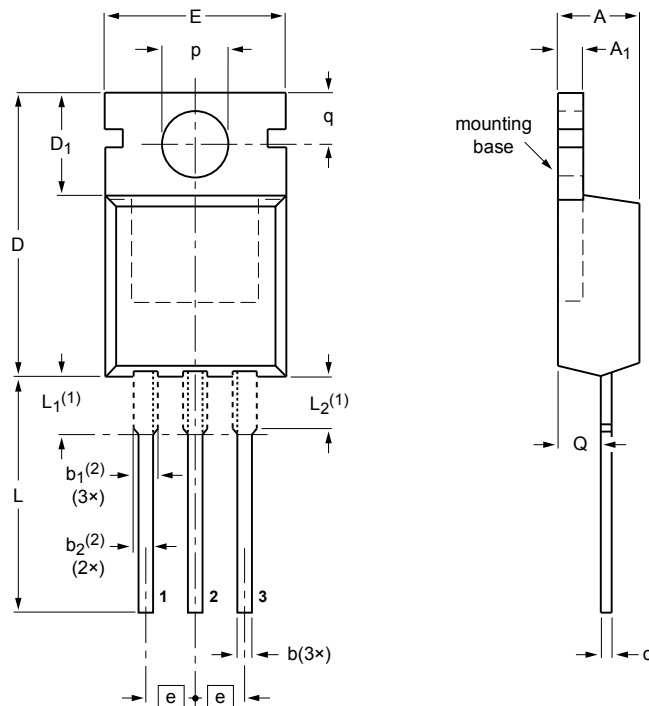


Fig 6. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

7. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	b ₁ (2)	b ₂ (2)	c	D	D ₁	E	e	L	L ₁ (1)	L ₂ (1) max.	p	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

Notes

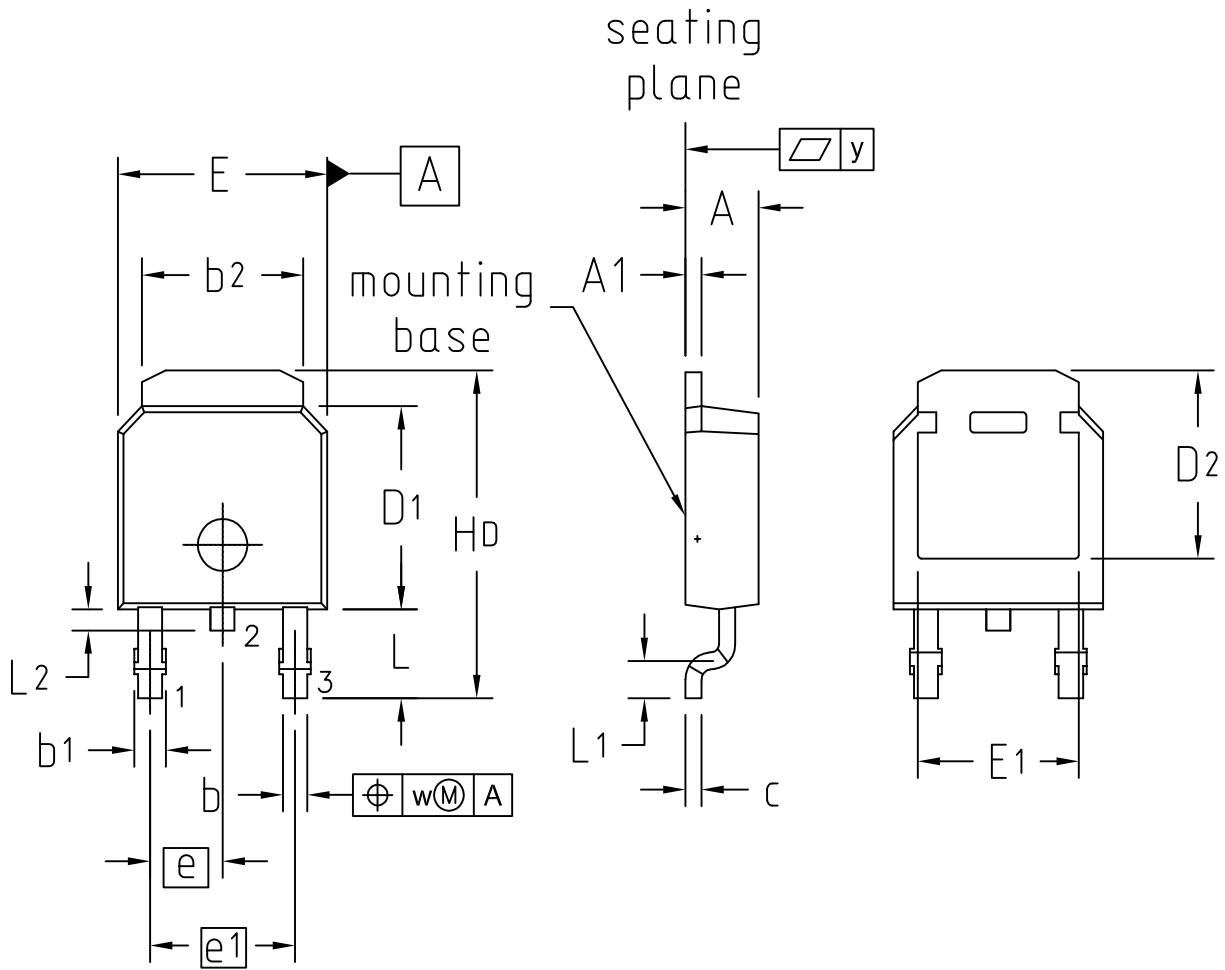
- Lead shoulder designs may vary.
- Dimension includes excess dambar.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT78		3-lead TO-220AB	SC-46		08-04-23 08-06-13

Fig 7. Package outline SOT78 (TO-220AB)

Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)

SOT428



UNIT	A	A ₁	b	b ₁	b ₂	c	D ₁	D ₂	E	E ₁	e	e ₁	H _d	L	L ₁	L ₂	w	y
mm	2.38	0.93	0.89	1.1	5.46	0.56	6.22	4.00	6.73	4.45	2.285	4.57	10.40	2.95	0.5	0.90	0.2	0.20
	2.22	0.46	0.71	0.9	5.00	0.20	5.98	min.	6.47	min.			9.60	2.55	min.	0.50		

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT428		TO-252				

Fig. 8. Package outline DPAK (SOT428)

8. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYQ28_SER_E_ED_4	20071205	Product data sheet	-	BYQ28E_SERIES_3
Modifications:	<ul style="list-style-type: none"> • The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Limiting values table: some parameter descriptions amended to conform to latest standards; I_{FRM} conditions amended; V_{ESD} row added. • Characteristics: Q_{rr} changed to Q_r 'recovered charge'; t_{rr1} and t_{rr2} changed to t_{rr} with 'ramp recovery' and 'step recovery' added to conditions. 			
BYQ28E_SERIES_3	19981001	Product specification	-	BYQ28E_SERIES_2
BYQ28E_SERIES_2	19980701	Product specification	-	BYQ28E_SERIES_1; BYQ28EB_SERIES_1
BYQ28E_SERIES_1; BYQ28EB_SERIES_1	19960801	Product specification	-	-

9. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ween-semi.com>.

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